Product specification

Logic level TOPFET

BUK148-50DL

DESCRIPTION

Monolithic temperature and overload protected logic level power MOSFET in TOPFET2 technology assembled in a 3 pin plastic package.

APPLICATIONS

General purpose switch for driving

- lamps
- motors
- solenoids
- heaters

in automotive systems and other applications.

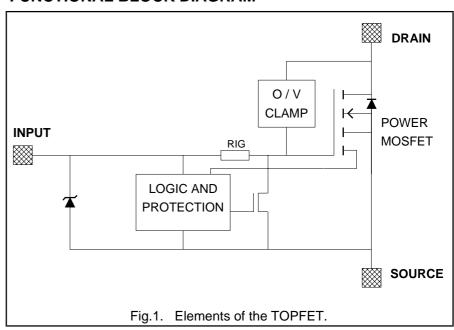
FEATURES

- TrenchMOS output stage
- **Current limiting**
- Overload protection
- Overtemperature protection Protection latched reset by input
- 5 V logic compatible input level
- Control of output stage and supply of overload protection circuits derived from input
- Low operating input current permits direct drive by micro-controller
- ESD protection on all pins
- Overvoltage clamping for turn off of inductive loads

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | UNIT |
|---|---|-----------------------------|-------------------------|
| $V_{DS} \\ I_{D} \\ P_{D} \\ T_{j} \\ R_{DS(ON)}$ | Continuous drain source voltage Continuous drain current Total power dissipation Continuous junction temperature Drain-source on-state resistance | 50 8 40 150 100 | V A W °C mΩ |
| I _{ISL} | Input supply current V _{IS} = 5 V | 650 | μА |

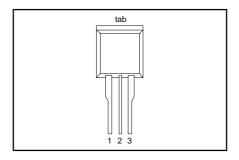
FUNCTIONAL BLOCK DIAGRAM



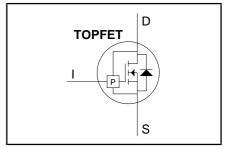
PINNING - SOT226

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | input |
| 2 | drain |
| 3 | source |
| tab | drain |

PIN CONFIGURATION



SYMBOL



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LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|--|--|------|---------|------|
| V _{DS} | Continuous drain source voltage ¹ | - | - | 50 | V |
| I _D | Continuous drain current | $V_{IS} = 5 \text{ V}; T_{mb} = 25 \text{ °C}$ | - | self - | Α |
| | | | | limited | |
| I _D | Continuous drain current | $V_{IS} = 5 \text{ V}; T_{mb} \le 110 \text{ °C}$ | - | 8 | Α |
| I ₁ | Continuous input current | - | -5 | 5 | mA |
| I _{IRM} | Non-repetitive peak input current | $t_p \le 1 \text{ ms}$ $T_{mb} \le 25 \text{ °C}$ | -10 | 10 | mA |
| P_{D} | Total power dissipation | T _{mb} ≤ 25 °C | - | 40 | W |
| T _{stg} | Storage temperature | - | -55 | 175 | °C |
| T _j | Continuous junction temperature ² | normal operation | - | 150 | °C |
| T_{sold} | Case temperature | during soldering | - | 260 | °C |

ESD LIMITING VALUE

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|----------------|---|---|------|------|------|
| V _C | Electrostatic discharge capacitor voltage | Human body model; C = 250 pF; R = 1.5 kΩ | - | 2 | kV |

OVERVOLTAGE CLAMPING LIMITING VALUES

At a drain source voltage above 50 V the power MOSFET is actively turned on to clamp overvoltage transients.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---|---|------|-----------|----------|
| E _{DSM} | Inductive load turn-off Non-repetitive clamping energy Repetitive clamping energy | $I_{DM} = 8 \text{ A}; V_{DD} \le 20 \text{ V}$ $T_{mb} \le 25 \text{ °C}$ $T_{mb} \le 95 \text{ °C}; f = 250 \text{ Hz}$ | | 100 20 | mJ mJ |

OVERLOAD PROTECTION LIMITING VALUE

With an adequate protection supply provided via the input pin, TOPFET can protect itself from two types of overload - overtemperature and short circuit load.

| SYMBOL | PARAMETER | REQUIRED CONDITION | MIN. | MAX. | UNIT |
|-----------------|-----------------------------------|--|------|------|------|
| V _{DS} | Drain source voltage ³ | $4 \text{ V} \leq \text{V}_{\text{IS}} \leq 5.5 \text{ V}$ | 0 | 35 | V |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------|--|------------|------|------|------|------|
| R _{th j-mb} | Thermal resistance Junction to mounting base | - | - | 2.5 | 3.1 | K/W |
| R _{th j-a} | Junction to ambient | | - | 50 | - | K/W |

¹ Prior to the onset of overvoltage clamping. For voltages above this value, safe operation is limited by the overvoltage clamping energy.

 $[\]textbf{2} \text{ A higher } T_j \text{ is allowed as an overload condition but at the threshold } T_{j(TO)} \text{ the over temperature trip operates to protect the switch.}$

³ All control logic and protection functions are disabled during conduction of the source drain diode.

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OUTPUT CHARACTERISTICS

Limits are for -40°C \leq T_{mb} \leq 150°C; typicals are for T_{mb} = 25 °C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---------------------|-------------------------------|---|------|------|------|------|
| | Off-state | $V_{IS} = 0 V$ | | | | |
| $V_{(CL)DSS}$ | Drain-source clamping voltage | I _D = 10 mA | 50 | - | - | V |
| | | $I_{DM} = 1 \text{ A}; t_p \le 300 \mu\text{s}; \delta \le 0.01$ | 50 | 60 | 70 | V |
| I _{DSS} | Drain source leakage current | V _{DS} = 40 V | - | - | 100 | μΑ |
| | | $T_{mb} = 25 ^{\circ}C$ | - | 0.1 | 10 | μΑ |
| | On-state | $I_{DM} = 3 \text{ A}; t_p \le 300 \mu\text{s}; \delta \le 0.01$ | | | | |
| R _{DS(ON)} | Drain-source resistance | $V_{IS} \ge 4.4 \text{ V}$ | - | - | 190 | mΩ |
| = = (0.1) | | $T_{mb} = 25 ^{\circ}C$ | - | 68 | 100 | mΩ |
| | | $V_{IS} \ge 4 V$ | - | - | 200 | mΩ |
| | | $T_{mb} = 25 ^{\circ}C$ | - | 72 | 105 | mΩ |

OVERLOAD CHARACTERISTICS

-40°C $\leq T_{mb} \leq 150^{\circ}C$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--|--|--|-----------|-----------|-----------|---------|
| I _D | Short circuit load Drain current limiting | | 9 8 | 12 - | 16 18 | A A |
| | | $4 \text{ V} \leq \text{V}_{IS} \leq 5.5 \text{ V}$ | 5 | - | 18 | Α |
| P _{D(TO)} T _{DSC} | Overload protection Overload power threshold Characteristic time | $V_{IS} = 5 \text{ V};$ $T_{mb} = 25 ^{\circ}\text{C}$ device trips if $P_D > P_{D(TO)}$ which determines trip time ¹ | 20 200 | 55 350 | 80 600 | W μs |
| | Overtemperature protection | | | | | |
| $T_{j(TO)}$ | Threshold junction temperature ² | | 150 | 170 | - | °C |

 $[\]textbf{1 Trip time } t_{d\,sc} \text{ varies with overload dissipation } P_D \text{ according to the formula } t_{d\,sc} \approx T_{DSC} \, / \, ln[\,\,P_D \, / \,\,P_{D(TO)}\,\,].$

 $[\]boldsymbol{2}$ This is independent of the dV/dt of input voltage $V_{\text{IS}}.$

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INPUT CHARACTERISTICS

The supply for the logic and overload protection is taken from the input. Limits are for $-40^{\circ}\text{C} \le T_{mb} \le 150^{\circ}\text{C}$; typicals are for $T_{mb} = 25^{\circ}\text{C}$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|---------------------|--|--|----------------------------------|------------|------------|------------|----------|
| V _{IS(TO)} | Input threshold voltage | $V_{DS} = 5 \text{ V}; I_{D} = 1 \text{ mA}$ | $T_{mb} = 25^{\circ}C$ | 0.6 1.1 | - 1.6 | 2.4 2.1 | V V |
| I _{IS} | Input supply current | normal operation; | $V_{IS} = 5 V$ $V_{IS} = 4 V$ | 100 80 | 220 195 | 400 330 | μΑ μΑ |
| I _{ISL} | Input supply current | protection latched; | $V_{IS} = 5 V$ $V_{IS} = 3 V$ | 200 130 | 400 250 | 650 430 | μA μA |
| V _{ISR} | Protection reset voltage ¹ | reset time t _r ≥ 100 μs | | 1.5 | 2 | 2.9 | V |
| t _{lr} | Latch reset time | $V_{IS1} = 5 \text{ V}, V_{IS2} < 1 \text{ V}$ | | 10 | 40 | 100 | μs |
| V _{(CL)IS} | Input clamping voltage | I _I = 1.5 mA | | 5.5 | - | 8.5 | V |
| R _{IG} | Input series resistance ² to gate of power MOSFET | | $T_{mb} = 25^{\circ}C$ | - | 33 | - | kΩ |

SWITCHING CHARACTERISTICS

 T_{mb} = 25 °C; V_{DD} = 13 V; resistive load R_L = 4 Ω . Refer to waveform figure and test circuit.

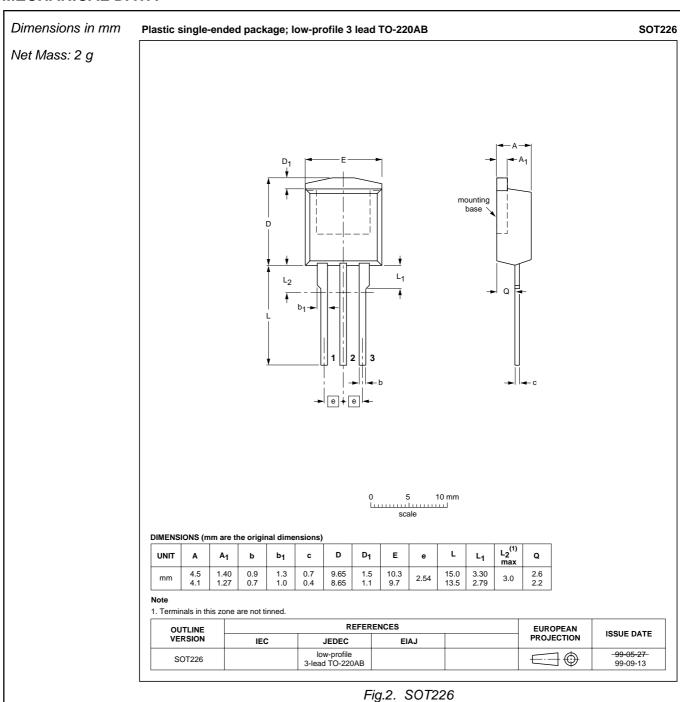
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|---------------------|-----------------------|------|------|------|------|
| t _{d on} | Turn-on delay time | V _{IS} = 5 V | - | 8 | 20 | μs |
| t _r | Rise time | | - | 20 | 50 | μs |
| t _{d off} | Turn-off delay time | $V_{IS} = 0 V$ | - | 25 | 70 | μs |
| t _f | Fall time | | - | 16 | 40 | μs |

¹ The input voltage below which the overload protection circuits will be reset.

² Not directly measureable from device terminals.

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MECHANICAL DATA



- Refer to mounting instructions for SOT226 package.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

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DEFINITIONS

| DATA SHEET STATU | IS | |
|-----------------------------------|--------------------------------|---|
| DATA SHEET STATUS ¹ | PRODUCT STATUS ² | DEFINITIONS |
| Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice |
| Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in ordere to improve the design and supply the best possible product |
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Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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